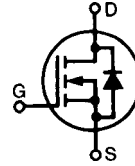


HiPerFET™ Power MOSFETs

IXFH/IXFM21N50
IXFH/IXFM/IXFT24N50
IXFH/IXFT26N50

N-Channel Enhancement Mode
High dv/dt, Low t_{rr} , HDMOS™ Family

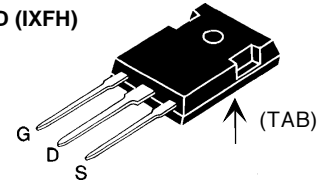


| V_{DSS} | I_{D25} | $R_{DS(on)}$ |
|-----------|-----------|---------------|
| 500 V | 21 A | 0.25 Ω |
| 500 V | 24 A | 0.23 Ω |
| 500 V | 26 A | 0.20 Ω |

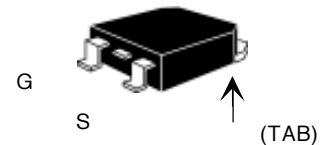
$t_{rr} \leq 250$ ns

| Symbol | Test Conditions | Maximum Ratings | |
|---------------|---|-----------------------------|------------------|
| V_{DSS} | $T_J = 25^\circ\text{C}$ to 150°C | 500 | V |
| V_{DGR} | $T_J = 25^\circ\text{C}$ to 150°C ; $R_{GS} = 1\text{ M}\Omega$ | 500 | V |
| V_{GS} | Continuous | ± 20 | V |
| V_{GSM} | Transient | ± 30 | V |
| I_{D25} | $T_C = 25^\circ\text{C}$ | 21N50 | 21 A |
| | | 24N50 | 24 A |
| | | 26N50 | 26 A |
| I_{DM} | $T_C = 25^\circ\text{C}$, pulse width limited by T_{JM} | 21N50 | 84 A |
| | | 24N50 | 96 A |
| | | 26N50 | 104 A |
| I_{AR} | $T_C = 25^\circ\text{C}$ | 21N50 | 21 A |
| | | 24N50 | 24 A |
| | | 26N50 | 26 A |
| E_{AR} | $T_C = 25^\circ\text{C}$ | 30 | mJ |
| dv/dt | $I_S \leq I_{DM}$, $di/dt \leq 100\text{ A}/\mu\text{s}$, $V_{DD} \leq V_{DSS}$, $T_J \leq 150^\circ\text{C}$, $R_G = 2\ \Omega$ | 5 | V/ns |
| P_D | $T_C = 25^\circ\text{C}$ | 300 | W |
| T_J | | -55 ... +150 | $^\circ\text{C}$ |
| T_{JM} | | 150 | $^\circ\text{C}$ |
| T_{stg} | | -55 ... +150 | $^\circ\text{C}$ |
| T_L | 1.6 mm (0.062 in.) from case for 10 s | 300 | $^\circ\text{C}$ |
| M_d | Mounting torque | 1.13/10 | Nm/lb.in. |
| Weight | | TO-204 = 18 g, TO-247 = 6 g | |

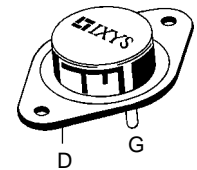
TO-247 AD (IXFH)



TO-268 (D3) Case Style



TO-204 AE (IXFM)



G = Gate, D = Drain,
S = Source, TAB = Drain

Features

- International standard packages
- Low $R_{DS(on)}$ HDMOS™ process
- Rugged polysilicon gate cell structure
- Unclamped Inductive Switching (UIS) rated
- Low package inductance
- easy to drive and to protect
- Fast intrinsic Rectifier

Applications

- DC-DC converters
- Synchronous rectification
- Battery chargers
- Switched-mode and resonant-mode power supplies
- DC choppers
- AC motor control
- Temperature and lighting controls
- Low voltage relays

Advantages

- Easy to mount with 1 screw (TO-247) (isolated mounting screw hole)
- High power surface mountable package
- High power density

| Symbol | Test Conditions | Characteristic Values ($T_J = 25^\circ\text{C}$, unless otherwise specified) | | |
|--------------|--|---|------|---------------------|
| | | min. | typ. | max. |
| V_{DSS} | $V_{GS} = 0\text{ V}$, $I_D = 250\ \mu\text{A}$ | 500 | | V |
| $V_{GS(th)}$ | $V_{DS} = V_{GS}$, $I_D = 4\text{ mA}$ | 2 | | V |
| I_{GSS} | $V_{GS} = \pm 20\text{ V}_{DC}$, $V_{DS} = 0$ | | | $\pm 100\text{ nA}$ |
| I_{DSS} | $V_{DS} = 0.8 \cdot V_{DSS}$ | $T_J = 25^\circ\text{C}$ | | 200 μA |
| | $V_{GS} = 0\text{ V}$ | $T_J = 125^\circ\text{C}$ | | 1 mA |



IXFH21N50
IXFM21N50

IXFH24N50
IXFM24N50
IXFT24N50

IXFH26N50
IXFM26N50
IXFT26N50

| Symbol | Test Conditions ($T_J = 25^\circ\text{C}$, unless otherwise specified) | Characteristic Values | | |
|--------------|--|-----------------------|------|---------------|
| | | Min. | Typ. | Max. |
| $R_{DS(on)}$ | $V_{GS} = 10\text{ V}, I_D = 0.5 I_{D25}$ Pulse test, $t \leq 300\ \mu\text{s}$, duty cycle $d \leq 2\%$ | 21N50 | | 0.25 Ω |
| | | 24N50 | | 0.23 Ω |
| | | 26N50 | | 0.20 Ω |
| g_{fs} | $V_{DS} = 10\text{ V}; I_D = 0.5 I_{D25}$, pulse test | 11 | 21 | S |
| C_{iss} | $V_{GS} = 0\text{ V}, V_{DS} = 25\text{ V}, f = 1\text{ MHz}$ | | 4200 | pF |
| C_{oss} | | | 450 | pF |
| C_{rss} | | | 135 | pF |
| $t_{d(on)}$ | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 V_{DSS}, I_D = 0.5 I_{D25}$ $R_G = 2\ \Omega$ (External) | | 16 | 25 ns |
| t_r | | | 33 | 45 ns |
| $t_{d(off)}$ | | | 65 | 80 ns |
| t_f | | | 30 | 40 ns |
| $Q_{g(on)}$ | $V_{GS} = 10\text{ V}, V_{DS} = 0.5 V_{DSS}, I_D = 0.5 I_{D25}$ | | 135 | 160 nC |
| Q_{gs} | | | 28 | 40 nC |
| Q_{gd} | | | 62 | 85 nC |
| R_{thJC} | (TO-247 Case Style) | | 0.25 | 0.42 K/W |
| R_{thCK} | | | | K/W |

Source-Drain Diode **Characteristic Values**
($T_J = 25^\circ\text{C}$, unless otherwise specified)

| Symbol | Test Conditions | Min. | Typ. | Max. |
|----------|---|---------------------------|------|---------------|
| I_S | $V_{GS} = 0\text{ V}$ | 21N50 | | 21 A |
| | | 24N50 | | 24 A |
| | | 26N50 | | 26 A |
| I_{SM} | Repetitive; pulse width limited by T_{JM} | 21N50 | | 84 A |
| | | 24N50 | | 96 A |
| | | 26N50 | | 104 A |
| V_{SD} | $I_F = I_S, V_{GS} = 0\text{ V}$, Pulse test, $t \leq 300\ \mu\text{s}$, duty cycle $d \leq 2\%$ | | | 1.5 V |
| t_{rr} | $I_F = I_S$ | $T_J = 25^\circ\text{C}$ | | 250 ns |
| | | $T_J = 125^\circ\text{C}$ | | 400 ns |
| Q_{RM} | $-di/dt = 100\text{ A}/\mu\text{s}$, $V_R = 100\text{ V}$ | $T_J = 25^\circ\text{C}$ | 1 | μC |
| | | $T_J = 125^\circ\text{C}$ | 2 | μC |
| I_{RM} | | $T_J = 25^\circ\text{C}$ | 10 | A |
| | | $T_J = 125^\circ\text{C}$ | 15 | A |

Note 1: Add "S" suffix for TO-247 SMD package option (ex: IXFH24N50S)

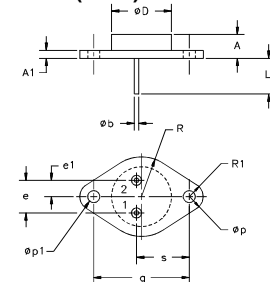
TO-247 AD (IXFH) Outline



Terminals:
1 - Gate
2 - Drain
3 - Source
Tab - Drain

| Dim. | Millimeter | | Inches | |
|-----------------|------------|-------|--------|-------|
| | Min. | Max. | Min. | Max. |
| A | 4.7 | 5.3 | .185 | .209 |
| A ₁ | 2.2 | 2.54 | .087 | .102 |
| A ₂ | 2.2 | 2.6 | .059 | .098 |
| b | 1.0 | 1.4 | .040 | .055 |
| b ₁ | 1.65 | 2.13 | .065 | .084 |
| b ₂ | 2.87 | 3.12 | .113 | .123 |
| C | .4 | .8 | .016 | .031 |
| D | 20.80 | 21.46 | .819 | .845 |
| E | 15.75 | 16.26 | .610 | .640 |
| e | 5.20 | 5.72 | 0.205 | 0.225 |
| L | 19.81 | 20.32 | .780 | .800 |
| L ₁ | | 4.50 | | .177 |
| $\varnothing P$ | 3.55 | 3.65 | .140 | .144 |
| Q | 5.89 | 6.40 | 0.232 | 0.252 |
| R | 4.32 | 5.49 | .170 | .216 |
| S | 6.15 | BSC | .242 | BSC |

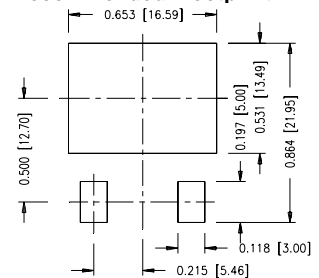
TO-204 AE (IXFM) Outline



Pins: 1 - Gate, 2 - Source, Case - Drain

| Dim. | Millimeter | | Inches | |
|-------------------|------------|-------|-----------|------|
| | Min. | Max. | Min. | Max. |
| A | 6.4 | 11.4 | .250 | .450 |
| A ₁ | 1.53 | 3.42 | .060 | .135 |
| $\varnothing b$ | 1.45 | 1.60 | .057 | .063 |
| $\varnothing D$ | | 22.22 | | .875 |
| e | 10.67 | 11.17 | .420 | .440 |
| e ₁ | 5.21 | 5.71 | .205 | .225 |
| L | 11.18 | 12.19 | .440 | .480 |
| $\varnothing p$ | 3.84 | 4.19 | .151 | .165 |
| $\varnothing p_1$ | 3.84 | 4.19 | .151 | .165 |
| q | 30.15 BSC | | 1.187 BSC | |
| R | 12.58 | 13.33 | .495 | .525 |
| R ₁ | 3.33 | 4.77 | .131 | .188 |
| s | 16.64 | 17.14 | .655 | .675 |

Min. Recommended Footprint



| SYM | INCHES | | MILLIMETERS | |
|----------------|----------|------|-------------|-------|
| | MIN | MAX | MIN | MAX |
| A | .193 | .201 | 4.90 | 5.10 |
| A ₁ | .106 | .114 | 2.70 | 2.90 |
| A ₂ | .001 | .010 | 0.02 | 0.25 |
| b | .045 | .057 | 1.15 | 1.45 |
| b ₂ | .075 | .083 | 1.90 | 2.10 |
| C | .016 | .026 | 0.40 | 0.65 |
| C ₂ | .057 | .063 | 1.45 | 1.60 |
| D | .543 | .551 | 13.80 | 14.00 |
| D ₁ | .488 | .500 | 12.40 | 12.70 |
| E | .624 | .632 | 15.85 | 16.05 |
| E ₁ | .524 | .535 | 13.30 | 13.60 |
| e | .215 BSC | | 5.45 BSC | |
| H | .736 | .752 | 18.70 | 19.10 |
| L | .094 | .106 | 2.40 | 2.70 |
| L ₁ | .047 | .055 | 1.20 | 1.40 |
| L ₂ | .039 | .045 | 1.00 | 1.15 |
| L ₃ | .010 BSC | | 0.25 BSC | |
| L ₄ | .150 | .161 | 3.80 | 4.10 |

IXYS reserves the right to change limits, test conditions, and dimensions.

IXYS MOSFETs and IGBTs are covered by one or more of the following U.S. patents: 4,835,592 4,881,106 5,017,508 5,049,961 5,187,117 5,486,715
4,850,072 4,931,844 5,034,796 5,063,307 5,237,481 5,381,025

Fig. 1 Output Characteristics



Fig. 2 Input Admittance

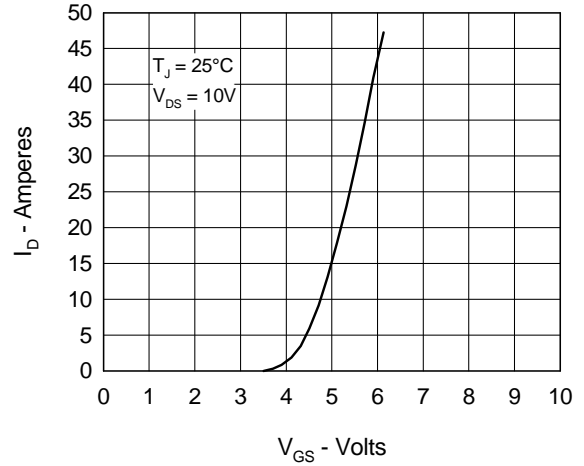


Fig. 3 $R_{DS(on)}$ vs. Drain Current



Fig. 4 Temperature Dependence of Drain to Source Resistance



Fig. 5 Drain Current vs. Case Temperature

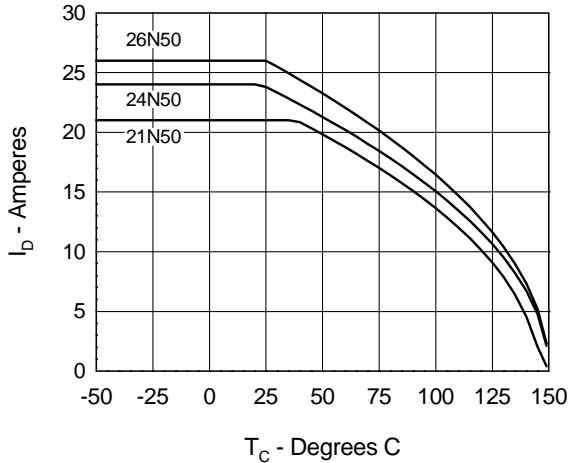


Fig. 6 Temperature Dependence of Breakdown and Threshold Voltage

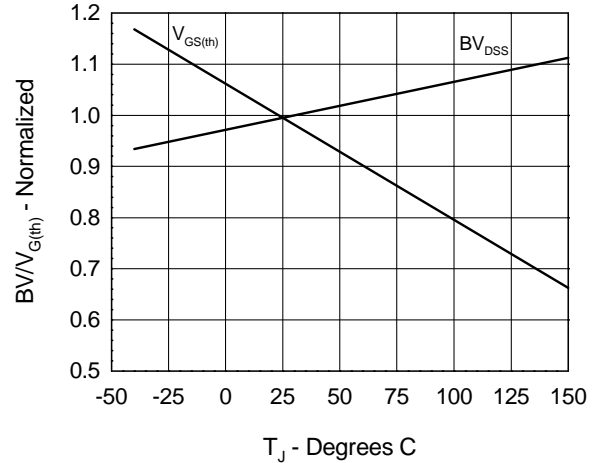


Fig.7 Gate Charge Characteristic Curve

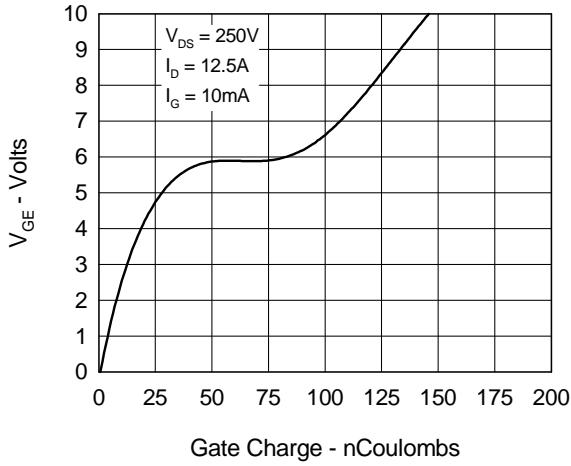


Fig.9 Capacitance Curves

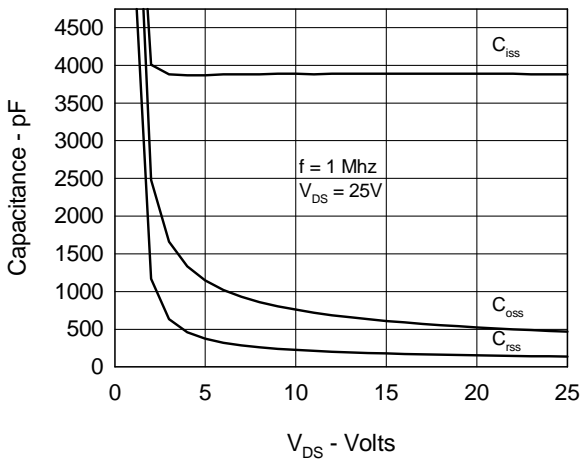


Fig.11 Transient Thermal Impedance

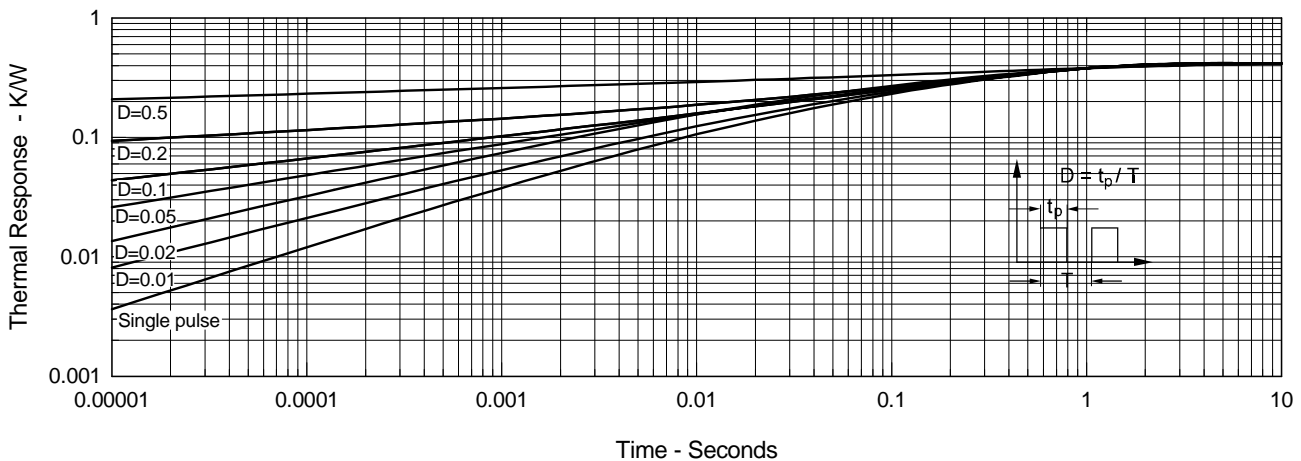


Fig.8 Forward Bias Safe Operating Area

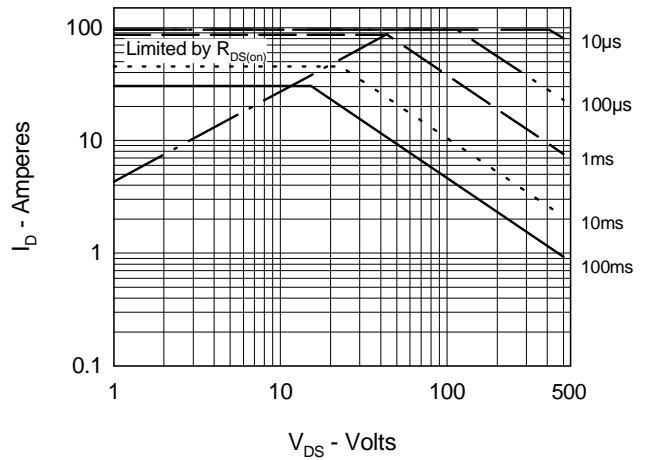


Fig.10 Source Current vs. Source to Drain Voltage

